FAIRCHILD

SEMICONDUCTOR

February 1990 Revised May 1999

MM74HCT573 • MM74HCT574 **Octal D-Type Latch • 3-STATE Octal D-Type Flip-Flop**

General Description

Ordering Codes:

The MM74HCT573 octal D-type latches and MM74HCT574 octal D-type flip-flop advanced silicon-gate CMOS technology, which provides the inherent benefits of low power consumption and wide power supply range, but are LS-TTL input and output characteristic and pin-out compatible. The 3-STATE outputs are capable of driving 15 LS-TTL loads. All inputs are protected from damage due to static discharge by internal diodes to V_{CC} and ground.

When the MM74HCT573 Latch Enable input is HIGH, the Q outputs will follow the D inputs. When the Latch Enable goes LOW, data at the D inputs will be retained at the outputs until Latch Enable returns HIGH again. When a high logic level is applied to the Output Control input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

The MM74HCT574 are positive edge triggered flip-flops. Data at the D inputs, meeting the setup and hold time requirements, are transferred to the Q outputs on positive

going transitions of the Clock (CK) input. When a high logic level is applied to the Output Control (OC) input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

The MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

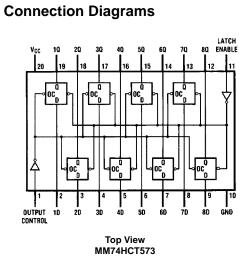
Features

- TTL input characteristic compatible
- Typical propagation delay: 18 ns
- Low input current: 1 µA maximum
- Low quiescent current: 80 µA maximum
- Compatible with bus-oriented systems
- Output drive capability: 15 LS-TTL loads

Order Number	Package Number	Package Description
MM74HCT573WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
MM74HCT573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wid
MM74HCT573N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
MM74HCT574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
MM74HCT574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
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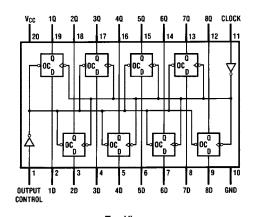


Truth Tables

MM74HCT573

Output Control	LE	Data	Output
L	Н	Н	Н
L	Н	L	L
L	L	Х	Q ₀
Н	Х	Х	Z

Z = High Impedance State



Top View **MM74HCT574**

ММ74НСТ574

Output Control	LE	Data	Output
L	↑ (Н	Н
L	↑ (L	L
L	L	Х	Q ₀
Н	Х	Х	Z

 $\label{eq:linear} \begin{array}{c} I = HIGH \mbox{ Level} \\ I = LOW \mbox{ Level} \\ Q_0 = Level \mbox{ of output before steady-state input conditions were established.} \end{array}$ X = Don't Care

Absolute Maximum Ratings(Note 1)

(Note 2)	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to $V_{CC}\text{+}$ 1.5V
DC Output Voltage (V _{OUT})	–0.5 to $V_{CC}\text{+}~0.5\text{V}$
Clamp Diode Current (I _{IK} , I _{OK})	\pm 20 mA
DC Output Current, per pin (I _{OUT})	\pm 35 mA
DC V_{CC} or GND Current, per pin (I _{CC})	\pm 70 mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P _D)	
(Note 3)	600 mW
S. O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

12 mW/°C from 65°C to 85°C.

	Min	Max	Units			
Supply Voltage (V _{CC})	4.5	5.5	V			
DC Input or Output Voltage						
(V _{IN} , V _{OUT})	0	V _{CC}	V			
Operating Temperature Range (T _A)	-40	+85	°C			
Input Rise or Fall Times						
t _r , t _f		500	ns			
Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.						
Note 2: Unless otherwise specified all voltages	are refere	enced to g	round.			
Note 3: Power Dissipation temperature derating	ıg — plas	tic "N" pa	ckage: -			

DC Electrical Characteristics

$V_{CC} = 5V \pm 10\%$ (unless otherwise specified) $T_A = 25^{\circ}C$ $T_A = -40 \text{ to } 85^\circ C \quad T_A = -55 \text{ to } 125^\circ C$ Symbol Parameter Conditions Units **Guaranteed Limits** Тур VIH Minimum HIGH Level 2.0 2.0 2.0 V Input Voltage Maximum LOW Level V_{IL} 0.8 0.8 0.8 V Input Voltage V_{ОН} Minimum HIGH Level $V_{IN} = V_{IH} \text{ or } V_{IL}$ Output Voltage $|I_{OUT}| = 20 \ \mu A$ V_{CC} V_{CC} - 0.1 V_{CC} - 0.1 V_{CC} - 0.1 V $|I_{OUT}| = 6.0$ mA, $V_{CC} = 4.5V$ 3.98 4.2 3.84 3.7 $|I_{OUT}| = 7.2 \text{ mA}, V_{CC} = 5.5 \text{V}$ 4.98 4.84 5.7 4.7 Maximum LOW Level V_{OL} $\mathsf{V}_{\text{IN}} = \mathsf{V}_{\text{IH}} \text{ or } \mathsf{V}_{\text{IL}}$ $|I_{OUT}| = 20 \ \mu A$ Voltage 0 0.1 0.1 0.1 V $|I_{OUT}| = 6.0 \text{ mA}, V_{CC} = 4.5 \text{V}$ 0.2 0.26 0.33 0.4 $|I_{OUT}| = 7.2 \text{ mA}, V_{CC} = 5.5 \text{V}$ 0.26 0.2 0.33 0.4 $V_{IN} = V_{CC}$ or GND, Maximum Input I_{IN} μΑ ±0.1 ±1.0 ±1.0 V_{IH} or V_{IL} Current Maximum 3-STATE $V_{OUT} = V_{CC} \text{ or } GND$ I_{OZ} Output Leakage $\text{Enable} = V_{\text{IH}} \text{ or } V_{\text{IL}}$ ±0.5 ±5.0 ±10 μΑ Current Maximum Quiescent $V_{IN} = V_{CC} \text{ or } GND$ I_{CC} 8.0 80 160 μΑ $I_{OUT} = 0 \ \mu A$ Supply Current V_{IN} = 2.4V or 0.5V (Note 4) 1.5 1.8 2.0 mΑ

Note 4: Measured per pin. All others tied to V_{CC} or ground.

VUC - 0.0	V, $t_r = t_f = 6 \text{ ns}$, $T_A = 25^{\circ}C$ (unless otherwise	specified)			
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL}	Maximum Propagation Delay	C _L = 45 pF	17	27	
t _{PLH}	Data to Output		17	27	ns
t _{PHL}	Maximum Propagation Delay	$C_L = 45 \text{ pF}$	16	27	ns
t _{PLH}	Latch Enable to Output		10	21	115
t _{PZH}	Maximum Enable Propagation Delay	$C_L = 45 \text{ pF}$	21	30	ns
t _{PZL}	Control to Output	$R_L = 1 \ k\Omega$	21	50	115
t _{PHZ}	Maximum Disable Propagation Delay	$C_L = 5 \text{ pF}$	14	23	ns
t _{PLZ}	Control to Output	$R_L = 1 \ k\Omega$	14	23	115
t _W	Minimum Clock Pulse Width			15	ns
t _S	Minimum Setup Time Data to Clock			5	ns
t _H	Minimum Hold Time Clock to Data			12	ns

AC Electrical Characteristics MM74HCT573

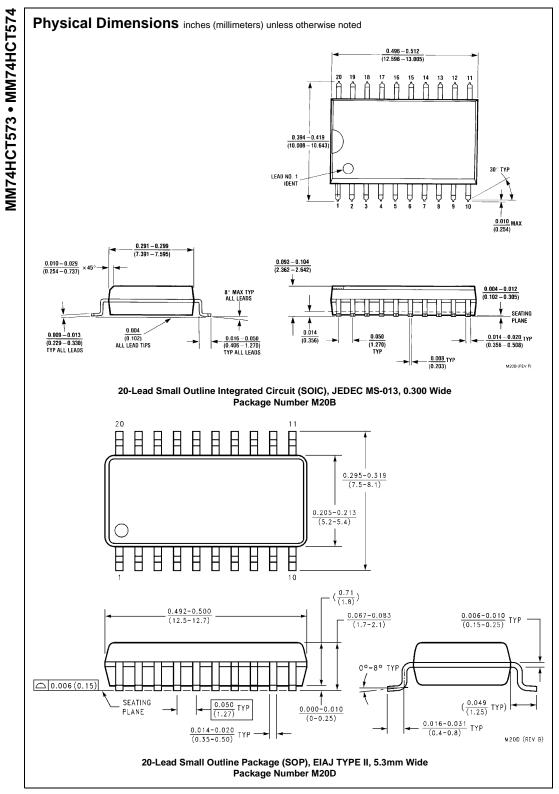
Symbol	Parameter	Conditions	$T_A = 25^{\circ}$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Gymbol		conditions	Тур		Guaranteed Li	mits	Onita
t _{PHL}	Maximum Propagation	$C_L = 50 \text{ pF}$	18	30	38	45	ns
t _{PLH}	Delay Data to Output		10 50		50	43	115
t _{PHL}	Maximum Propagation Delay	$C_L = 50 \text{ pF}$	17	30	44	53	ns
t _{PLH}	Latch Enable to Output			50		53	115
t _{PZH}	Maximum Enable Propagation	$C_L = 50 \text{ pF}$	22	30	38	45	ns
t _{PZL}	Delay Control to Output	$R_L = 1 \ k\Omega$	22	30	50	40	115
t _{PHZ}	Maximum Disable Propagation	$C_L = 50 \text{ pF}$	15	30	38	45	ns
t _{PLZ}	Delay Control to Output	$R_L = 1 \ k\Omega$					115
t _{THL}	Maximum Output	$C_L = 50 \text{ pF}$	6	12	15	18	ns
t _{TLH}	Rise and Fall Time		0	12	15	10	115
t _W	Minimum Clock Pulse Width			15	20	24	ns
t _S	Minimum Setup Time Data to Clock		-3	5	6	8	ns
t _H	Minimum Hold Time Clock to Data		4	12	15	18	ns
C _{IN}	Maximum Input Capacitance			10	10	10	pF
C _{OUT}	Maximum Output Capacitance			20	20	20	pF
C _{PD}	Power Dissipation Capacitance	$OC = V_{CC}$		5			pF
	(Note 5)	OC = GND		52			h-

$V_{CC} = 5.0$	V , $t_f = t_f = 6$ ns, $T_A = 25^{\circ}C$				
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f _{MAX}	Maximum Clock Frequency		60	33	MHz
t _{PHL}	Maximum Propagation Delay	C _L = 45 pF	17	27	
t _{PLH}	to Output		17	21	ns
t _{PZH}	Maximum Enable Propagation Delay	C _L = 45 pF	19	28	ns
t _{PZL}	Control to Output	$R_L = 1 \ k\Omega$	19	20	115
t _{PHZ}	Maximum Disable Propagation Delay	C _L = 45 pF	14	25	ns
t _{PLZ}	Control to Output	$R_L = 1 \ k\Omega$	14	25	115
t _W	Minimum Clock Pulse Width			15	ns
t _S	Minimum Setup Time Data to Clock		İ	12	ns
t _H	Minimum Hold Time Clock to Data			5	ns

AC Electrical Characteristics MM74HCT574 $V_{CC} = 5.0V \pm 10\%$, $t_r = t_f = 6$ ns (unless otherwise specified)

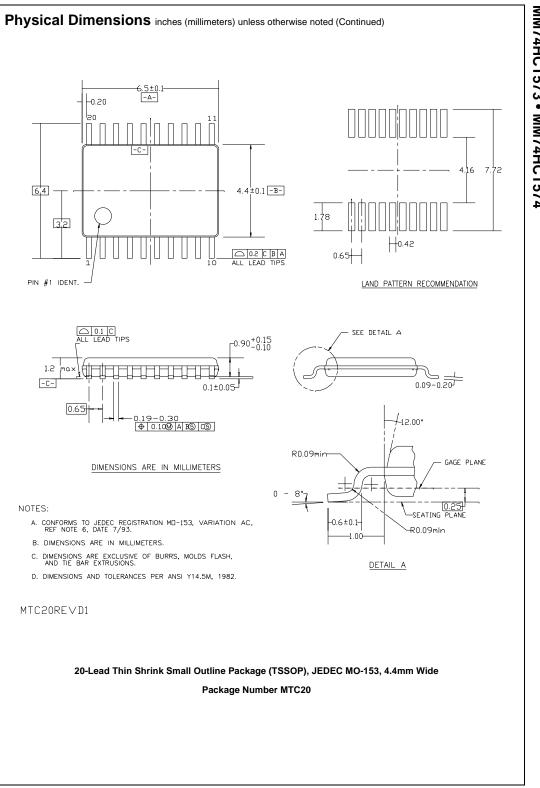
Symbol	Parameter	Conditions	T _A = 2	5°C	$T_A = -40$ to $85^{\circ}C$	$T_{A}=-55$ to $125^{\circ}C$	Units
Symbol			Тур	Guaranteed Limits			Units
f _{MAX}	Maximum Clock Frequency			33	28	23	MHz
t _{PHL}	Maximum Propagation Delay	$C_L = 50 \text{ pF}$	18	30	38	45	ns
t _{PLH}	Clock to Output		10		38		115
t _{PZH}	Maximum Enable Propagation	$C_L = 50 \text{ pF}$	22	22 30	30 38	45	ns
t _{PZL}	Delay Control to Output	$R_L = 1 \ k\Omega$	22				115
t _{PHZ}	Maximum Disable Propagation	$C_L = 50 \text{ pF}$	15	30	38	45	ns
t _{PLZ}	Delay Control to Output	$R_L = 1 \ k\Omega$	15		30		115
t _{THL}	Maximum Output	$C_L = 50 \text{ pF}$	6	12	15	18	ns
t _{TLH}	Rise and Fall Time		0	12	15	10	115
t _W	Minimum Clock Pulse Width			15	20	24	ns
t _S	Minimum Setup Time Data to Clock		6	12	15	18	ns
t _H	Minimum Hold Time Clock to Data		-1	5	6	8	ns
C _{IN}	Maximum Input Capacitance			10	10	10	pF
C _{OUT}	Maximum Output Capacitance			20	20	20	pF
CPD	Power Dissipation Capacitance	$OC = V_{CC}$	5				pF
	(Note 6)	OC = GND	58				рг

Note 6: C_{PD} determines the no load power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

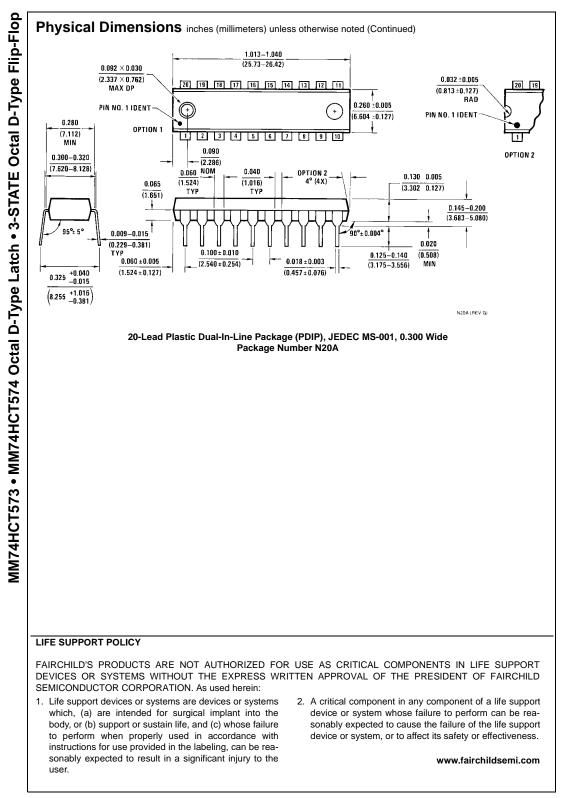


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